



BCW66 series

45 V, 800 mA NPN general-purpose transistor

Rev. 1 — 21 April 2017

Product data sheet

1 General description

NPN general-purpose transistors in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

PNP complements: BCW68F/G/H

2 Features and benefits

- High current
- AEC-Q101 qualified

3 Applications

- General-purpose switching and amplification

4 Quick reference data

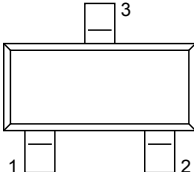
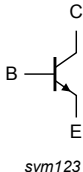
Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CE0}	collector-emitter voltage	open base	-	-	45	V
I_C	collector current		-	-	800	mA
I_{CM}	peak collector current	single pulse; $t_p \leq 1$ ms	-	-	1	A
h_{FE}	DC current gain	$V_{CE} = 1$ V; $I_C = 100$ mA; $T_{amb} = 25$ °C	[1]			
	BCW66F			100	-	250
	BCW66G			160	-	400
	BCW66H			250	-	600

[1] pulsed: $t_p \leq 300$ μ s, $\delta \leq 0.02$

5 Pinning information

Table 2. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	B	base		 sym123
2	E	emitter		
3	C	collector		

6 Ordering information

Table 3. Ordering information

Type number	Package		Version
	Name	Description	
BCW66F	TO-236AB	plastic surface-mounted package; 3 leads	SOT23
BCW66G			
BCW66H			

7 Marking

Table 4. Marking

Type number	Marking code
BCW66F	[1] EQ%
BCW66G	[1] ER%
BCW66H	[1] ES%

[1] % = placeholder for manufacturing site code

8 Limiting values

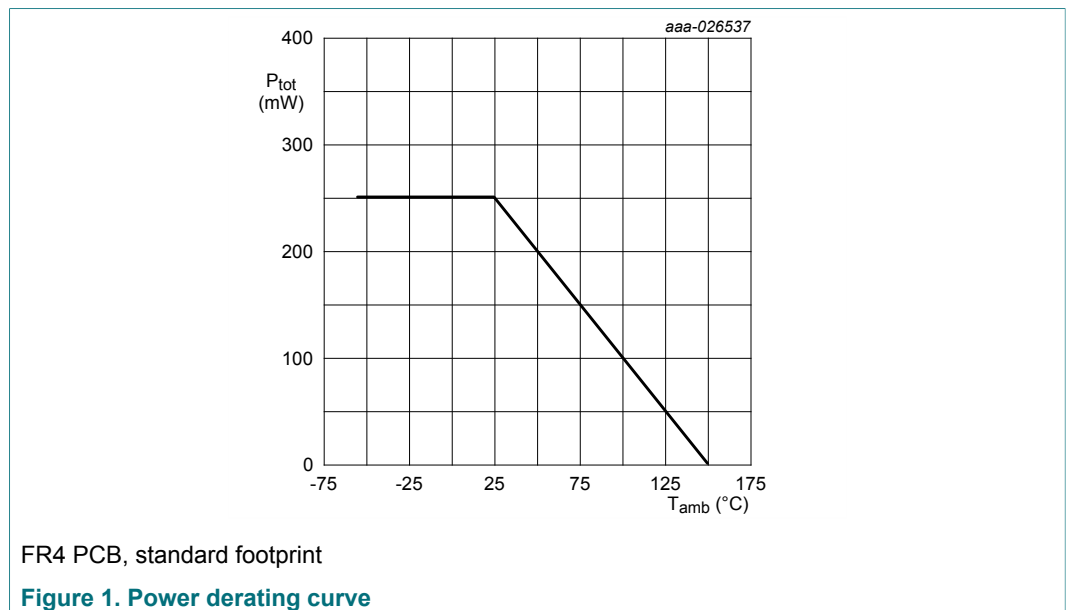
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter	-	50	V
V_{CEO}	collector-emitter voltage	open base	-	45	V
V_{EBO}	emitter-base voltage	open collector	-	5	V
I_C	collector current		-	800	mA
I_{CM}	peak collector current	single pulse; $t_p \leq 1$ ms	-	1	A
I_B	base current		-	100	mA

Symbol	Parameter	Conditions	Min	Max	Unit
I_{BM}	peak base current	single pulse; $t_p \leq 1$ ms	-	200	mA
P_{tot}	total power dissipation	$T_{amb} \leq 25$ °C [1]	-	250	mW
T_j	junction temperature		-	150	°C
T_{amb}	ambient temperature		-55	150	°C
T_{stg}	storage temperature		-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit-Board (PCB), single-sided chopper, tin-plated and standard footprint.

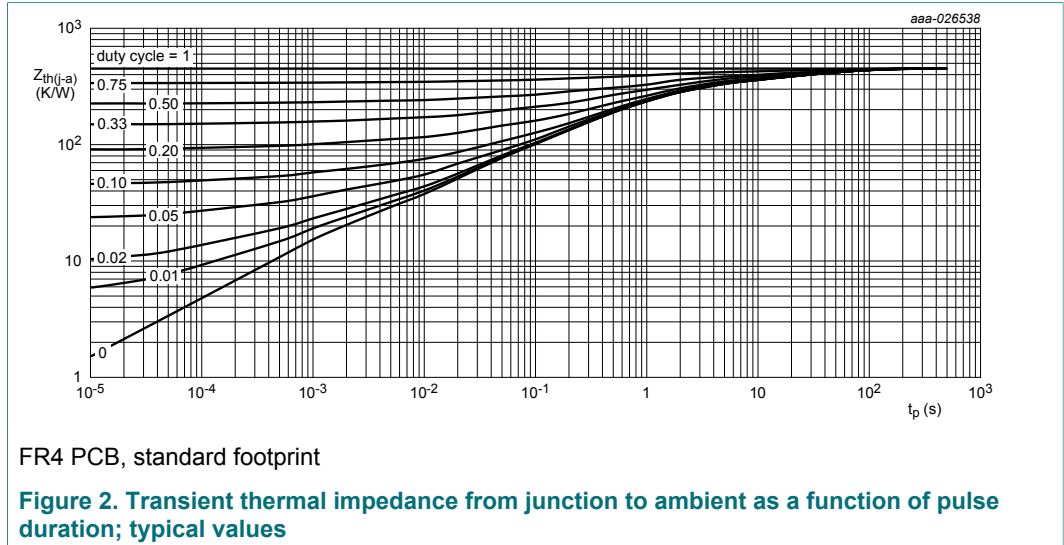


9 Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air [1]	-	-	500	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.



10 Electrical characteristics

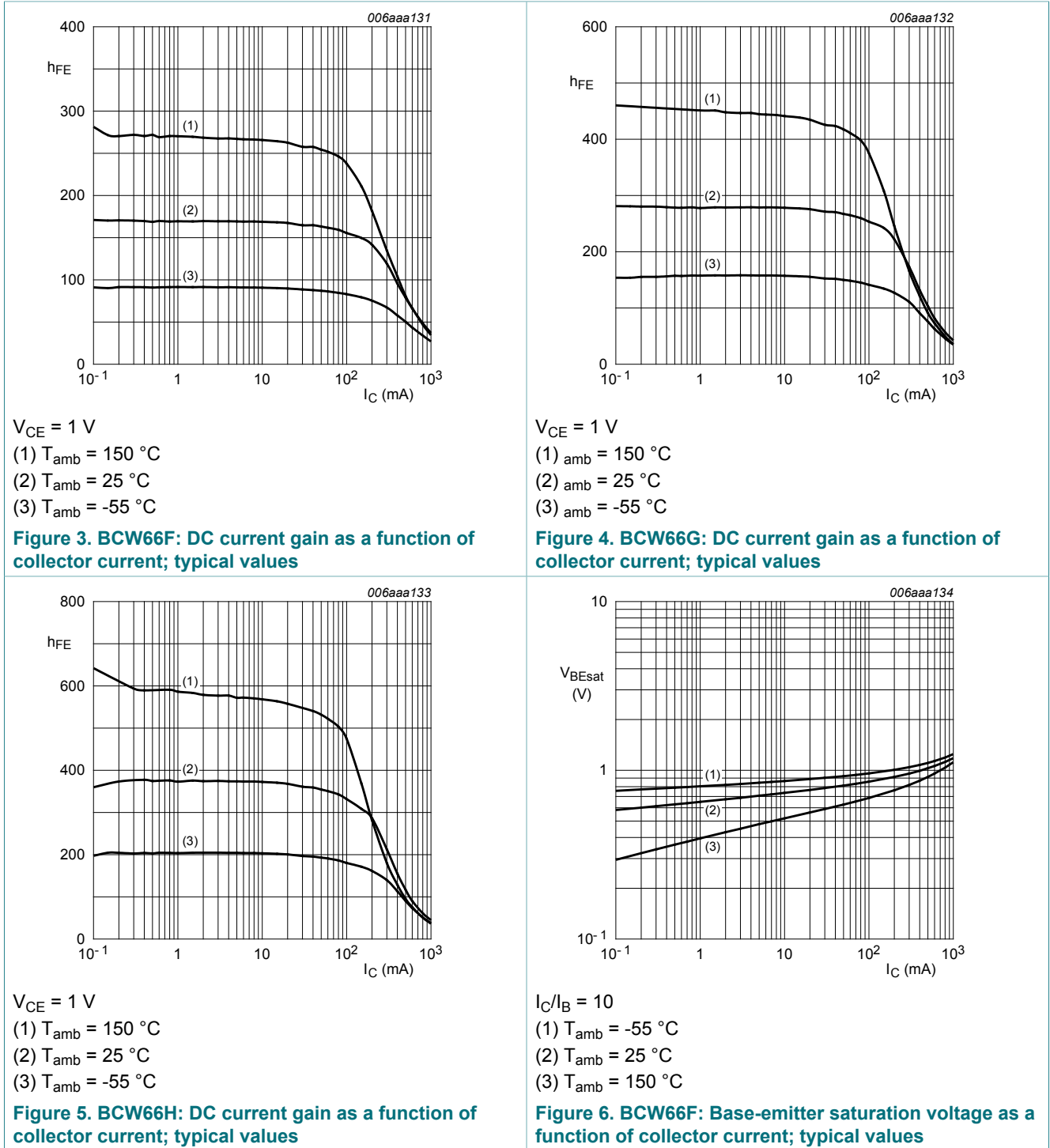
Table 7. Electrical characteristics

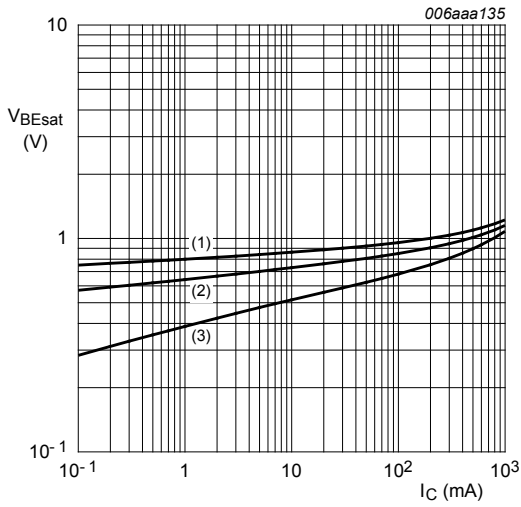
$T_{amb} = 25\text{ °C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
I_{CBO}	collector-base cut-off current	$V_{CB} = 40\text{ V}; I_E = 0\text{ A}$	-	-	20	nA	
		$V_{CB} = 40\text{ V}; I_E = 0\text{ A}; T_j = 150\text{ °C}$	-	-	5	μA	
I_{EBO}	emitter-base cut-off current	$V_{EB} = 5\text{ V}; I_C = 0\text{ A}$	-	-	20	nA	
h_{FE}	DC current gain						
	BCW66F/G/H	$V_{CE} = 1\text{ V}; I_C = 100\text{ }\mu\text{A}$	75	-	-		
	BCW66F/G/H	$V_{CE} = 1\text{ V}; I_C = 1\text{ mA}$	75	-	-		
	BCW66F/G/H	$V_{CE} = 1\text{ V}; I_C = 10\text{ mA}$	75	-	-		
	BCW66F	$V_{CE} = 1\text{ V}; I_C = 100\text{ mA}$	[1]	100	-	250	
	BCW66G		[1]	160	-	400	
	BCW66H		[1]	250	-	630	
BCW66F/G/H	$V_{CE} = 1\text{ V}; I_C = 500\text{ mA}$	[1]	40	-	-		
V_{CEsat}	collector-emitter saturation voltage	$I_C = 100\text{ mA}; I_B = 10\text{ mA}$	[1]	-	-	350	mV
		$I_C = 500\text{ mA}; I_B = 50\text{ mA}$	[1]	-	-	450	mV
V_{BEsat}	base-emitter saturation voltage	$I_C = 100\text{ mA}; I_B = 10\text{ mA}$	[1]	-	-	1.25	V
		$I_C = 500\text{ mA}; I_B = 50\text{ mA}$	[1]	-	-	1.25	V
f_T	transition frequency	$V_{CE} = 5\text{ V}; I_C = 10\text{ mA}; f = 100\text{ MHz}$	100	-	-	MHz	
C_c	collector capacitance	$V_{CB} = 10\text{ V}; I_E = I_e = 0\text{ A}; f = 1\text{ MHz}$	-	3	-	pF	

[1] pulsed; $t_p \leq 300\text{ }\mu\text{s}$; $\delta \leq 0.02$

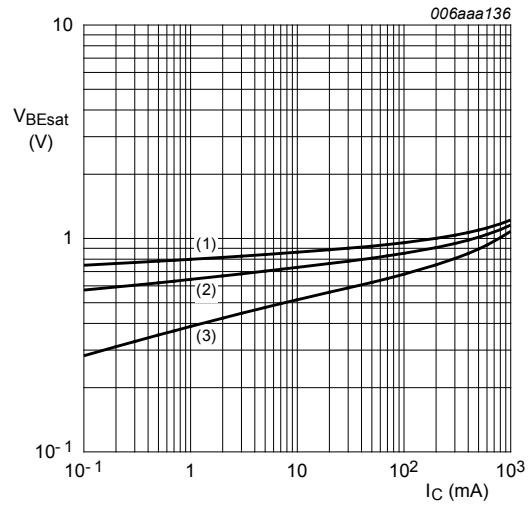
Table 8.





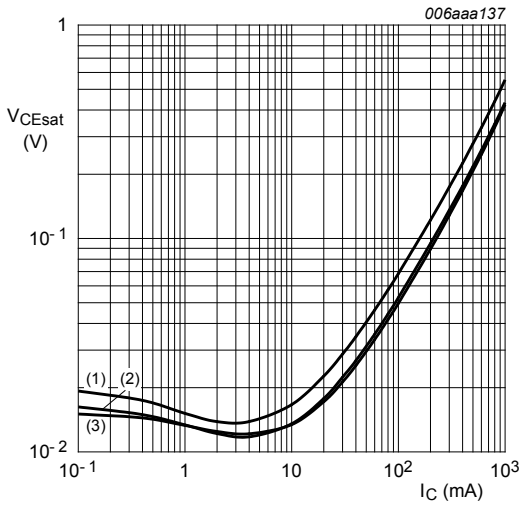
$I_C/I_B = 10$
 (1) $T_{amb} = -55\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = 150\text{ °C}$

Figure 7. BCW66G: Base-emitter saturation voltage as a function of collector current; typical values



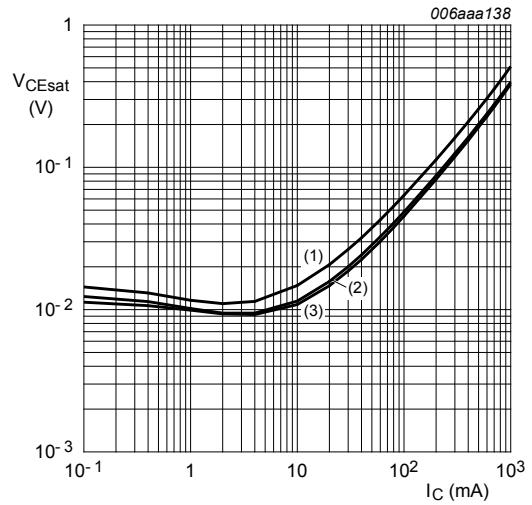
$I_C/I_B = 10$
 (1) $T_{amb} = -55\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = 150\text{ °C}$

Figure 8. BCW66H: Base-emitter saturation voltage as a function of collector current; typical values



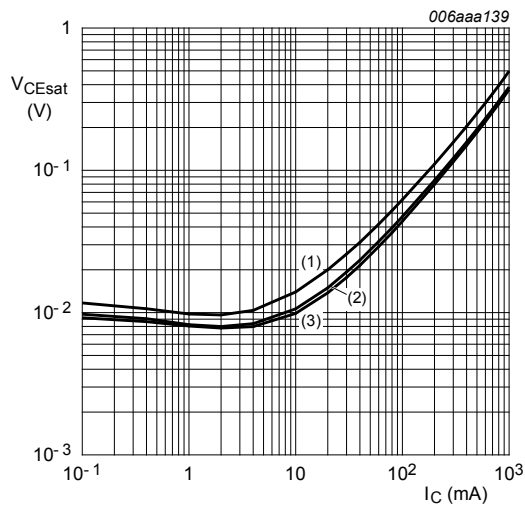
$I_C/I_B = 10$
 (1) $T_{amb} = 150\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = -55\text{ °C}$

Figure 9. BCW66F: Collector-emitter saturation voltage as a function of collector current; typical values



$I_C/I_B = 10$
 (1) $T_{amb} = 150\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = -55\text{ °C}$

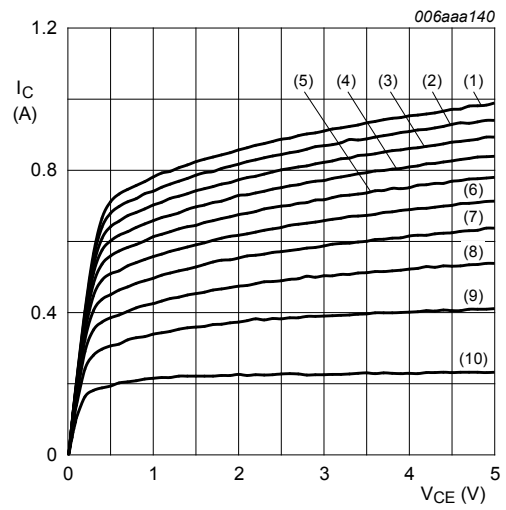
Figure 10. BCW66G: Collector-emitter saturation voltage as a function of collector current; typical values



$I_C/I_B = 10$

- (1) $T_{amb} = 150\text{ °C}$
- (2) $T_{amb} = 25\text{ °C}$
- (3) $T_{amb} = -55\text{ °C}$

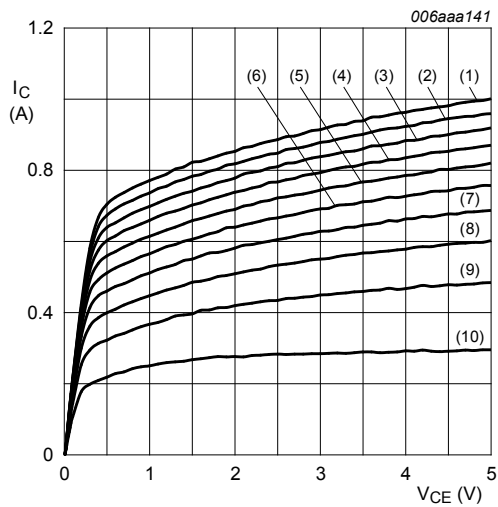
Figure 11. BCW66H: Collector-emitter saturation voltage as a function of collector current; typical values



$T_{amb} = 25\text{ °C}$

- (1) $I_B = 16.0\text{ mA}$
- (2) $I_B = 14.4\text{ mA}$
- (3) $I_B = 12.8\text{ mA}$
- (4) $I_B = 11.2\text{ mA}$
- (5) $I_B = 9.6\text{ mA}$
- (6) $I_B = 8.0\text{ mA}$
- (7) $I_B = 6.4\text{ mA}$
- (8) $I_B = 4.8\text{ mA}$
- (9) $I_B = 3.2\text{ mA}$
- (10) $I_B = 1.6\text{ mA}$

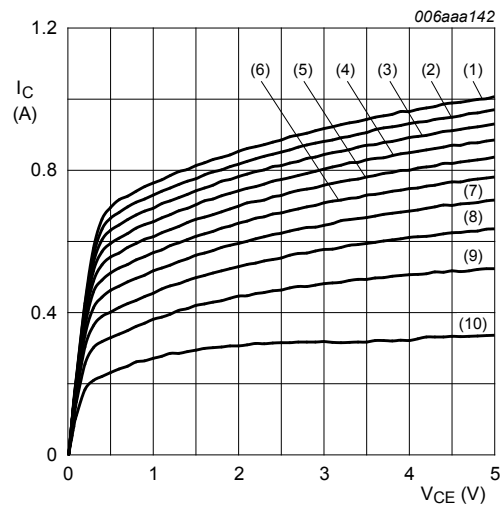
Figure 12. BCW66F: Collector current as a function of collector-emitter voltage; typical values



$T_{amb} = 25\text{ }^{\circ}\text{C}$

- (1) $I_B = 13.0\text{ mA}$
- (2) $I_B = 11.7\text{ mA}$
- (3) $I_B = 10.4\text{ mA}$
- (4) $I_B = 9.1\text{ mA}$
- (5) $I_B = 7.8\text{ mA}$
- (6) $I_B = 6.5\text{ mA}$
- (7) $I_B = 5.2\text{ mA}$
- (8) $I_B = 3.9\text{ mA}$
- (9) $I_B = 2.6\text{ mA}$
- (10) $I_B = 1.3\text{ mA}$

Figure 13. BCW66G: Collector current as a function of collector-emitter voltage; typical values



$T_{amb} = 25\text{ }^{\circ}\text{C}$

- (1) $I_B = 12.0\text{ mA}$
- (2) $I_B = 10.8\text{ mA}$
- (3) $I_B = 9.6\text{ mA}$
- (4) $I_B = 8.4\text{ mA}$
- (5) $I_B = 7.2\text{ mA}$
- (6) $I_B = 6.0\text{ mA}$
- (7) $I_B = 4.8\text{ mA}$
- (8) $I_B = 3.6\text{ mA}$
- (9) $I_B = 2.4\text{ mA}$
- (10) $I_B = 1.2\text{ mA}$

Figure 14. BCW66H: Collector current as a function of collector-emitter voltage; typical values

11 Test information

11.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

12 Package outline

Table 9. Package outline

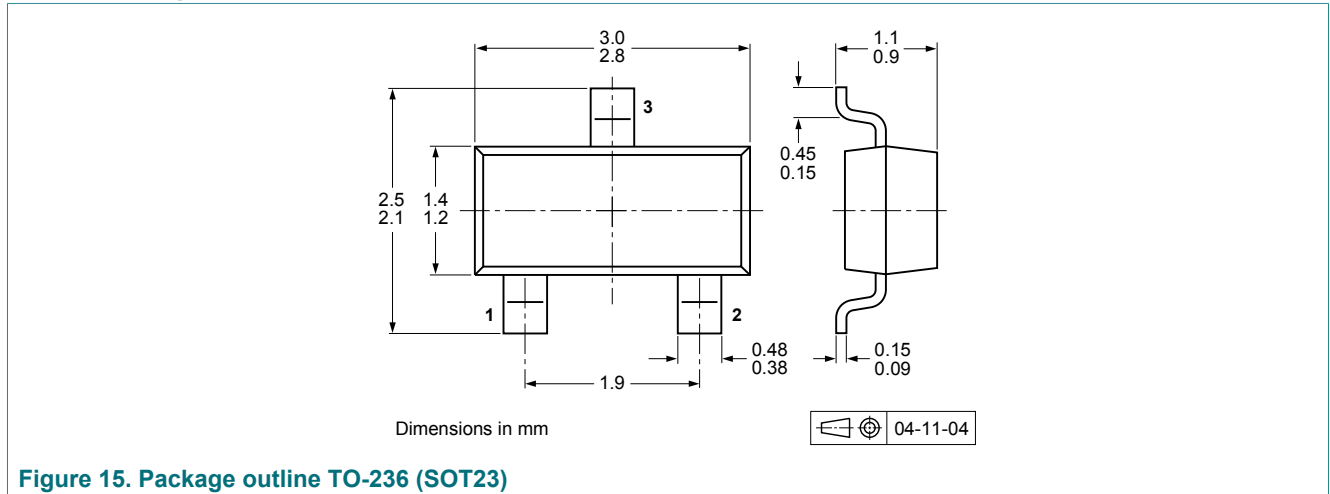


Figure 15. Package outline TO-236 (SOT23)

13 Soldering

Table 10. Soldering

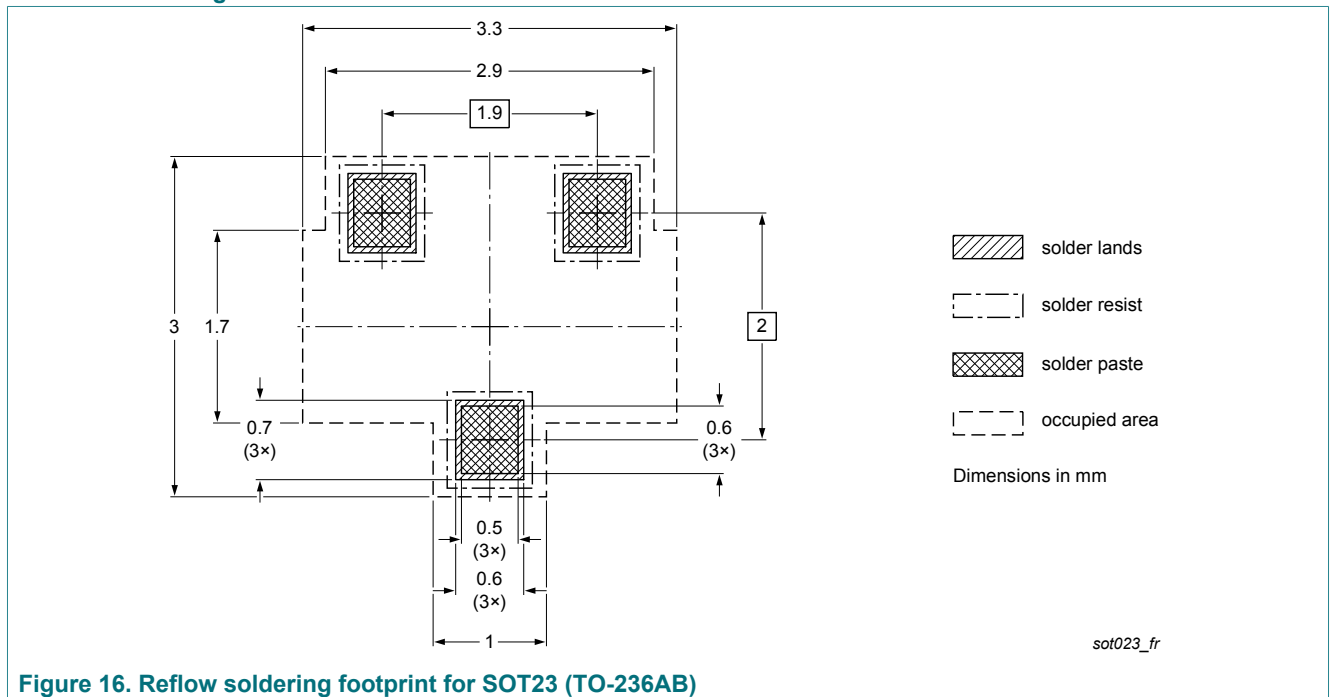
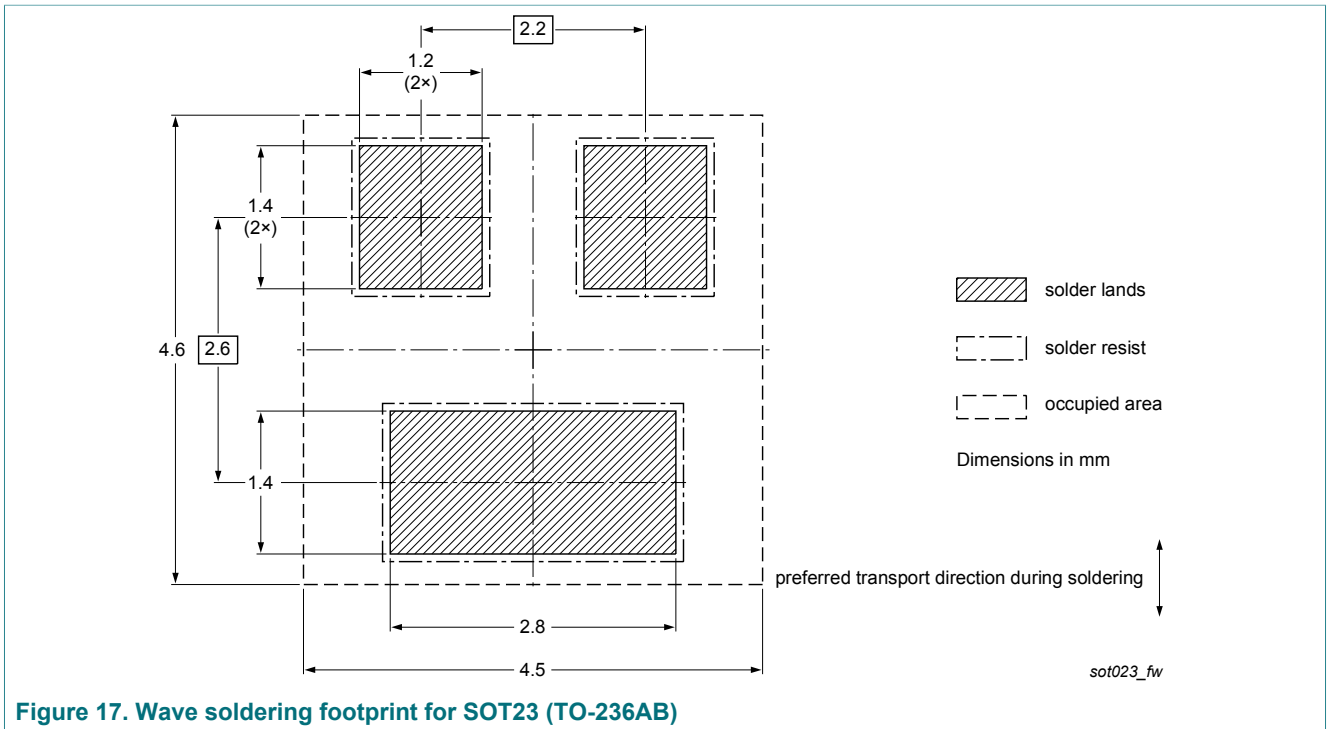


Figure 16. Reflow soldering footprint for SOT23 (TO-236AB)



14 Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BCW66x_SER v.1	21 April 2017	Product data sheet	-	-

15 Legal information

15.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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Tables

Tab. 1.	Quick reference data	1	Tab. 7.	Electrical characteristics	4
Tab. 2.	Pinning	2	Tab. 8.	5
Tab. 3.	Ordering information	2	Tab. 9.	Package outline	9
Tab. 4.	Marking	2	Tab. 10.	Soldering	9
Tab. 5.	Limiting values	2	Tab. 11.	Revision history	10
Tab. 6.	Thermal characteristics	3			

Figures

Fig. 1.	Power derating curve	3	Fig. 9.	BCW66F: Collector-emitter saturation voltage as a function of collector current; typical values	6
Fig. 2.	Transient thermal impedance from junction to ambient as a function of pulse duration; typical values	4	Fig. 10.	BCW66G: Collector-emitter saturation voltage as a function of collector current; typical values	6
Fig. 3.	BCW66F: DC current gain as a function of collector current; typical values	5	Fig. 11.	BCW66H: Collector-emitter saturation voltage as a function of collector current; typical values	7
Fig. 4.	BCW66G: DC current gain as a function of collector current; typical values	5	Fig. 12.	BCW66F: Collector current as a function of collector-emitter voltage; typical values	7
Fig. 5.	BCW66H: DC current gain as a function of collector current; typical values	5	Fig. 13.	BCW66G: Collector current as a function of collector-emitter voltage; typical values	8
Fig. 6.	BCW66F: Base-emitter saturation voltage as a function of collector current; typical values	5	Fig. 14.	BCW66H: Collector current as a function of collector-emitter voltage; typical values	8
Fig. 7.	BCW66G: Base-emitter saturation voltage as a function of collector current; typical values	6	Fig. 15.	Package outline TO-236 (SOT23)	9
Fig. 8.	BCW66H: Base-emitter saturation voltage as a function of collector current; typical values	6	Fig. 16.	Reflow soldering footprint for SOT23 (TO-236AB)	9
			Fig. 17.	Wave soldering footprint for SOT23 (TO-236AB)	10

Contents

1	General description	1
2	Features and benefits	1
3	Applications	1
4	Quick reference data	1
5	Pinning information	2
6	Ordering information	2
7	Marking	2
8	Limiting values	2
9	Thermal characteristics	3
10	Electrical characteristics	4
11	Test information	8
11.1	Quality information	8
12	Package outline	9
13	Soldering	9
14	Revision history	10
15	Legal information	11

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